

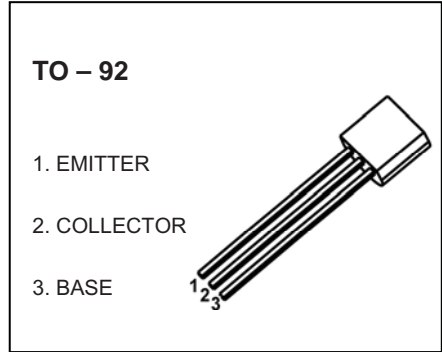


**TO-92 Plastic-Encapsulate Transistors**

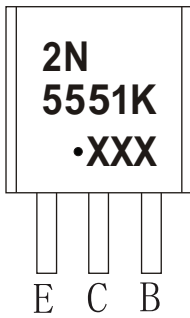
**2N5551K** TRANSISTOR (NPN)

**FEATURES**

- General Purpose Switching Application

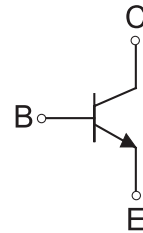


**MARKING**



2N5551K=Device code  
 Solid dot=Green molding compound device,  
 if none,the normal device  
 XXX=Code

**Equivalent Circuit**



**ORDERING INFORMATION**

Part Number	Package	Packing Method	Pack Quantity
2N5551K	TO-92	Bulk	1000pcs/Bag
2N5551K-TA	TO-92	Tape	2000pcs/Box

**MAXIMUM RATINGS (T<sub>a</sub>=25°C unless otherwise noted)**

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	180	V
V <sub>CEO</sub>	Collector-Emitter Voltage	160	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
I <sub>C</sub>	Collector Current -Continuous	0.6	A
P <sub>D</sub>	Collector Power Dissipation	625	mW
R <sub>θJA</sub>	Thermal Resistance from Junction to Ambient	200	°C /W
T <sub>J</sub> ,T <sub>stg</sub>	Operation Junction and Storage Temperature Range	-55 ~+150	°C

## ELECTRICAL CHARACTERISTICS

$T_a=25^\circ\text{C}$  unless otherwise specified

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=100\mu\text{A}, I_E=0$	180			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}^*$	$I_C=1\text{mA}, I_B=0$	160			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=10\mu\text{A}, I_C=0$	6			V
Collector cut-off current	$I_{CBO}$	$V_{CB}=120\text{V}, I_E=0$			50	nA
Emitter cut-off current	$I_{EBO}$	$V_{EB}=4\text{V}, I_C=0$			50	nA
DC current gain	$h_{FE(1)}$	$V_{CE}=5\text{V}, I_C=1\text{mA}$	80			
	$h_{FE(2)}$	$V_{CE}=5\text{V}, I_C=10\text{mA}$	80		300	
	$h_{FE(3)}$	$V_{CE}=5\text{V}, I_C=50\text{mA}$	50			
Collector-emitter saturation voltage	$V_{CE(sat) (1)}$	$I_C=10\text{mA}, I_B=1\text{mA}$			0.15	V
	$V_{CE(sat) (2)}$	$I_C=50\text{mA}, I_B=5\text{mA}$			0.2	V
Base-emitter saturation voltage	$V_{BE(sat) (1)}$	$I_C=10\text{mA}, I_B=1\text{mA}$			1	V
	$V_{BE(sat) (2)}$	$I_C=50\text{mA}, I_B=5\text{mA}$			1	V
Collector output capacitance	$C_{ob}$	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$			6	pF
Emitter input capacitance	$C_{ib}$	$V_{BE}=0.5\text{V}, I_C=0, f=1\text{MHz}$			20	pF
Transition frequency	$f_T$	$V_{CE}=10\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	100		300	MHz

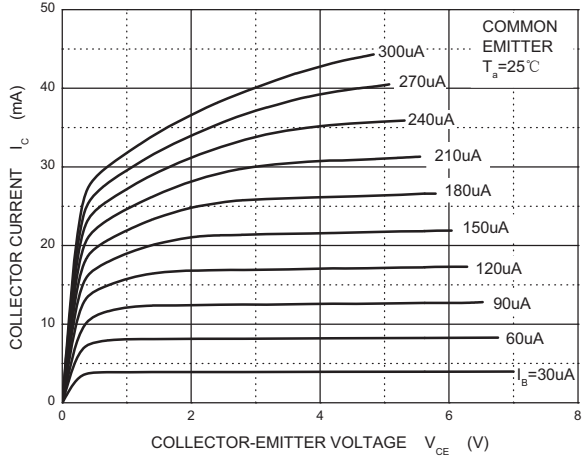
\*Pulse test: pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2.0\%$ .

### CLASSIFICATION OF $h_{FE(2)}$

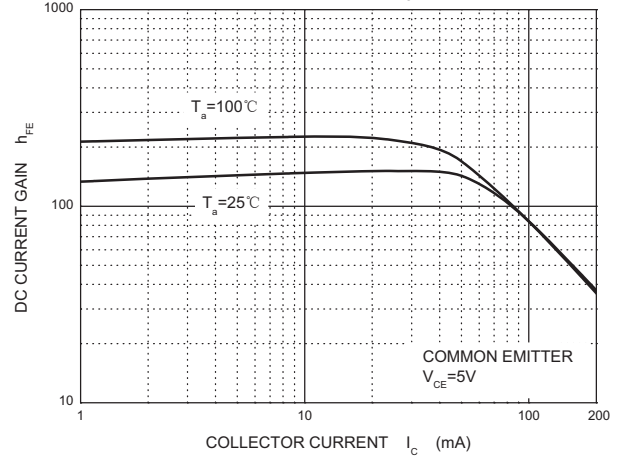
RANK		A	B	C
RANGE	80-100	100-150	150-200	200-300

# Typical Characteristics

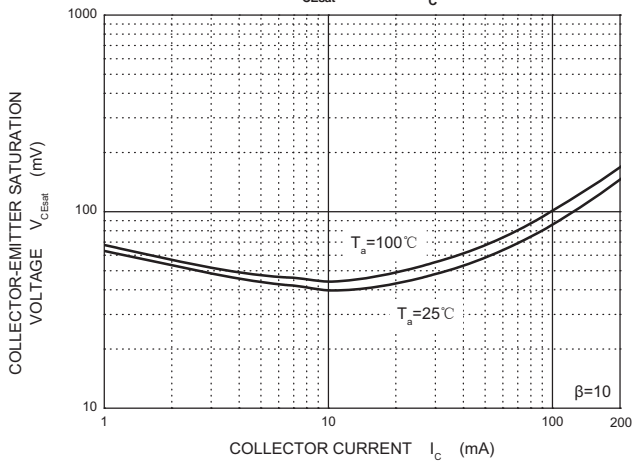
Static Characteristic



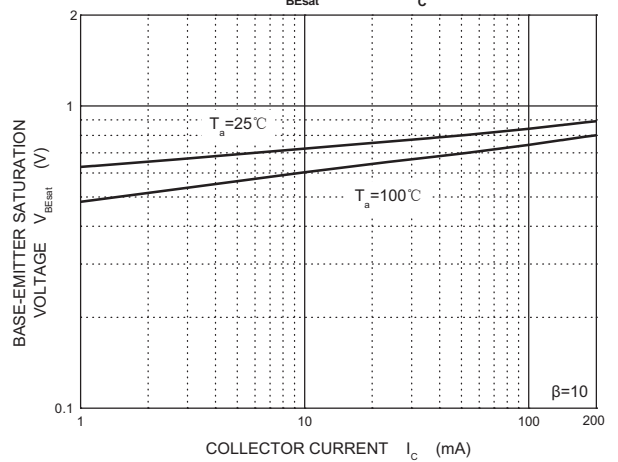
$h_{FE}$  —  $I_C$



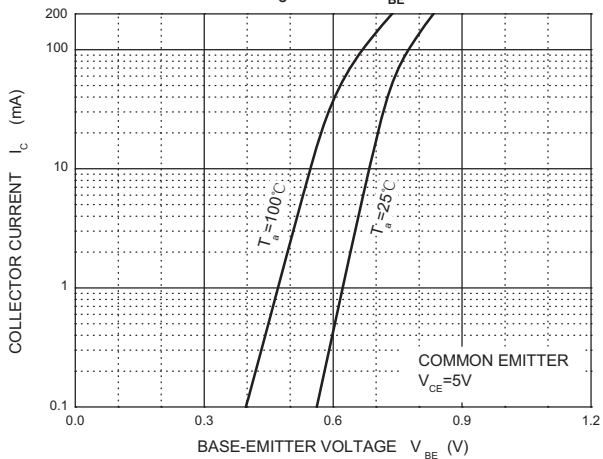
$V_{CEsat}$  —  $I_C$



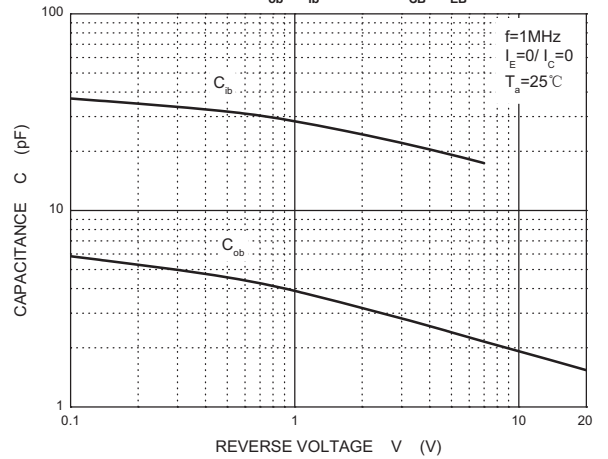
$V_{BEsat}$  —  $I_C$



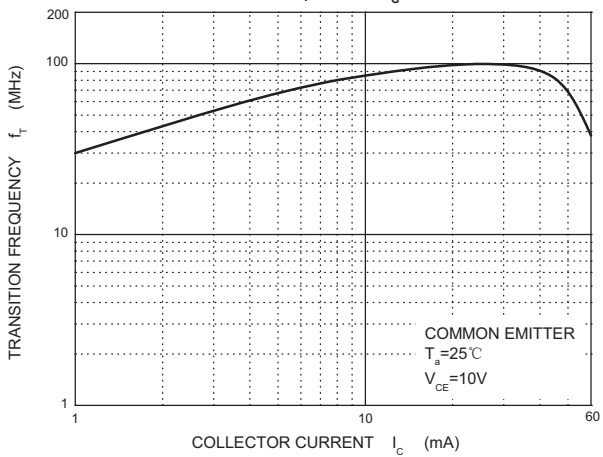
$I_C$  —  $V_{BE}$



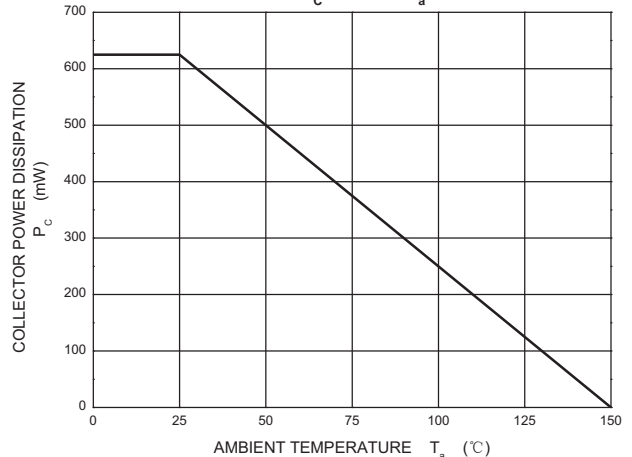
$C_{ob}/C_{ib}$  —  $V_{CB}/V_{EB}$



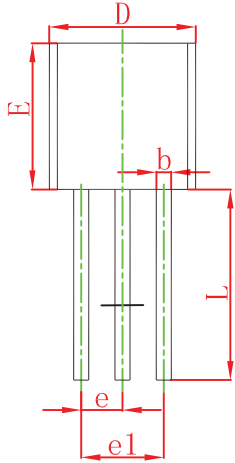
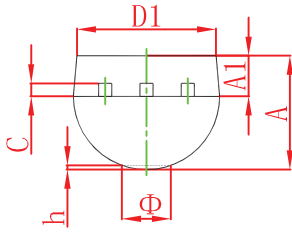
$f_T$  —  $I_C$



$P_C$  —  $T_a$

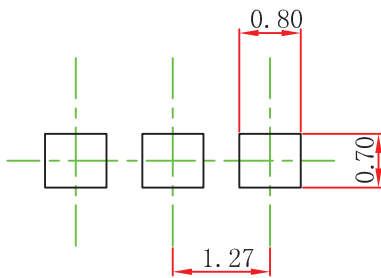


## TO-92 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.300	4.700	0.169	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270 TYP		0.050 TYP	
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
Φ		1.600		0.063
h	0.000	0.380	0.000	0.015

## TO-92 Suggested Pad Layout



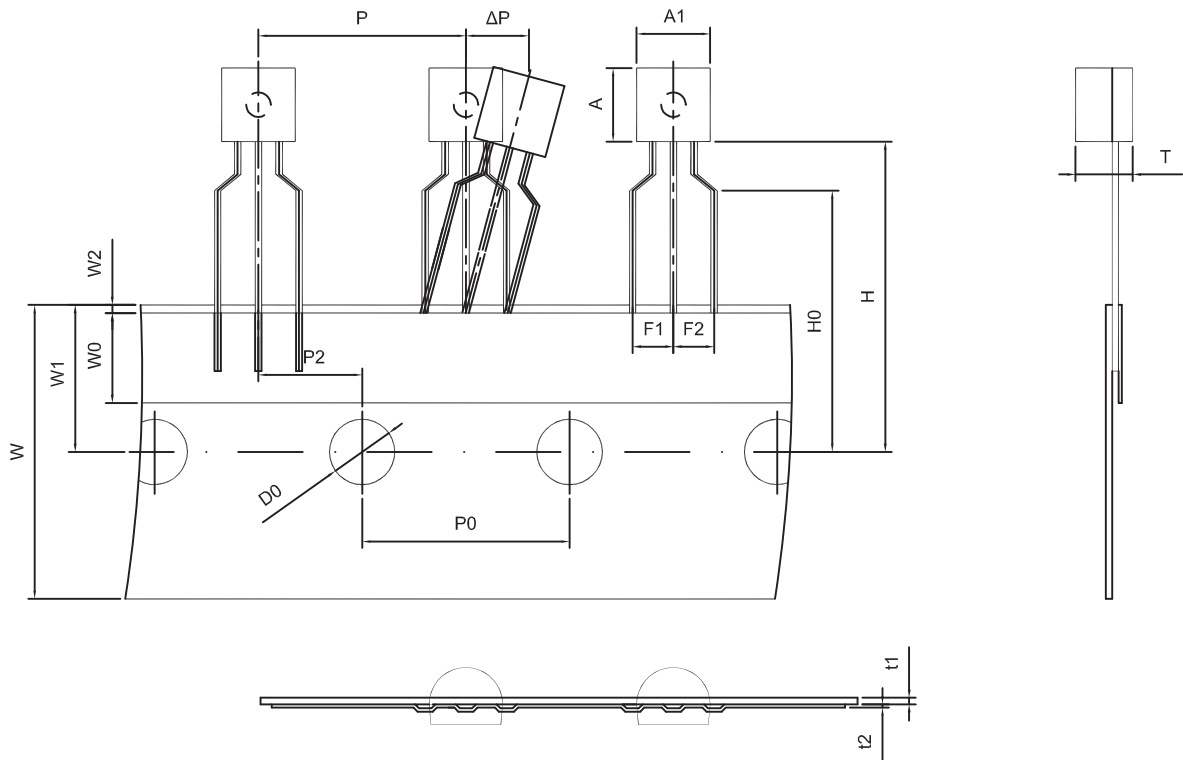
### Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.

### NOTICE

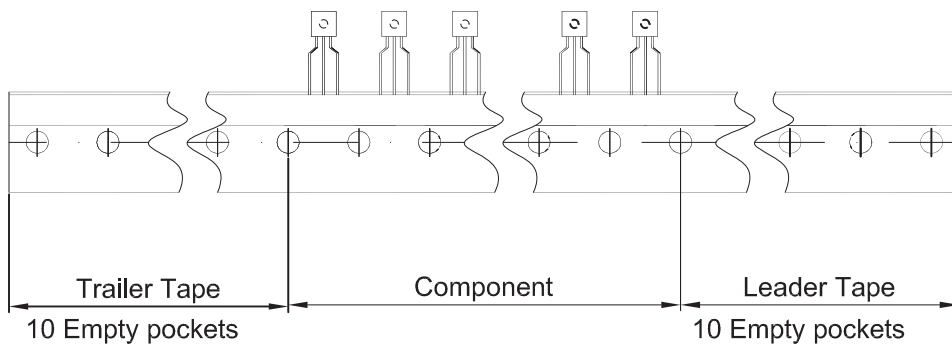
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# TO-92 Tape and Reel



Dimiensions are in millimeter

A1	A	T	P	P0	P2	F1	F2	W
4.5	4.5	3.5	12.7	12.7	6.35	2.5	2.5	18.0
W0	W1	W2	H	H0	D0	t1	t2	$\Delta P$
6.0	9.0	1.0 MAX.	19.0	16.0	4.0	0.4	0.2	0



Package	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92	2000 pcs	333×162×43	20,000 pcs	350×340×250